

# Eiji Kamiyama

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/2097144/publications.pdf>

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5  
papers

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citations

2681738

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2272555

4  
g-index

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docs citations

5  
times ranked

9  
citing authors

#	ARTICLE	IF	CITATIONS
1	Stability of Excess Oxygen Atoms near Oxide Precipitate and Oxygen Solubility in Silicon Crystal. ECS Journal of Solid State Science and Technology, 2018, 7, P102-P108.	0.9	5
2	Prediction of O Aggregation in Straight Line at High Temperature in Si Crystals: Thermal Donors Attaching to an Oxide Precipitate Surface. ECS Journal of Solid State Science and Technology, 2020, 9, 054003.	0.9	3
3	(Invited) Applications of the Hakoniwa Method to Impurity Atoms Wandering Inside Si Wafers. ECS Transactions, 2021, 102, 39-50.	0.3	1
4	Differential clustering of self-interstitials during Si crystal growth. Journal of Crystal Growth, 2021, 574, 126313.	0.7	1
5	(Invited) Applications of the Hakoniwa Method to Impurity Atoms Wandering Inside Si Wafers. ECS Meeting Abstracts, 2021, MA2021-01, 1095-1095.	0.0	0